XS3A1T3157

Low-ohmic single-pole double-throw analog switch

Rev. 1 — 17 March 2020 Product data sheet

1. General description

The XS3A1T3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y1 and Y2) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC}. This makes it possible for the XS3A1T3157 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The XS3A1T3157 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y1 or Y2, or from Y1 or Y2 to Z. It's low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.6 Ω (typical) at V_{CC} = 1.4 V
  - 1.0 Ω (typical) at V_{CC} = 1.65 V
  - 0.55 Ω (typical) at V_{CC} = 2.3 V
  - 0.50 Ω (typical) at V_{CC} = 2.7 V
  - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 exceeds 8000 V
  - CDM ANSI/ESDA/JEDEC JS-002 exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Low-switching threshold levels
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

nexperia

3. Applications

- Mobile phone
- Tablet / Notebook
- Wearables

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
XS3A1T3157GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
XS3A1T3157GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202

5. Marking

Table 2. Marking codes

Type number	Marking code[1]
XS3A1T3157GM	aL
XS3A1T3157GS	aL

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

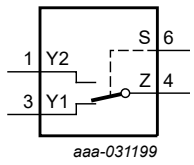


Fig. 1. Logic symbol

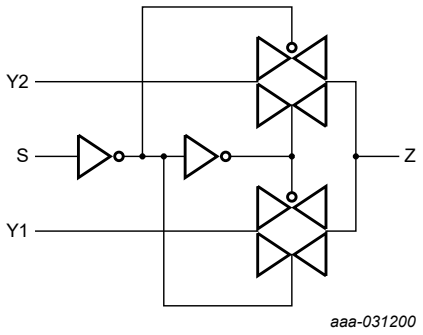
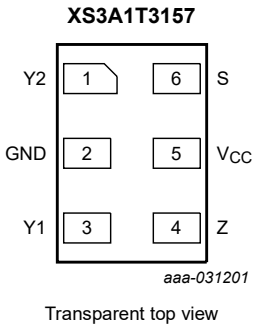


Fig. 2. Logic diagram

7. Pinning information

7.1. Pinning



Transparent top view

Fig. 3. Pin configuration SOT886 (XSON6) and SOT1202 (XSON6)

7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
Y2	1	independent input or output
GND	2	ground (0 V)
Y1	3	independent input or output
Z	4	common output or input
V_{CC}	5	supply voltage
S	6	select input

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input S	Channel on
L	Y1
H	Y2

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_I	input voltage	select input S [1]	-0.5	+4.6	V
V_{SW}	switch voltage	[2]	-0.5	V_{CC} + 0.5	V
I_{IK}	input clamping current	V_I < -0.5 V	-50	-	mA
I_{SK}	switch clamping current	V_I < -0.5 V or V_I > V_{CC} + 0.5 V	-	±50	mA
I_{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C [3]	-	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.
[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.
[3] For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.
For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
V_I	input voltage	select input S	0	4.3	V
V_{SW}	switch voltage	[1]	0	V_{CC}	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V [2]	-	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.
[2] Applies to control signal levels.

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T_{amb} = 25 °C			T_{amb} = −40 °C to +85 °C		T_{amb} = −40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V_{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	0.9	-	V
		V_{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	0.9	-	V
		V_{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	1.1	-	V
		V_{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	1.3	-	V
		V_{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	1.4	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	-	0.3	V
		V_{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	-	0.3	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	-	0.4	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	-	0.5	V
		V_{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	-	0.6	V
I_I	input leakage current	select input S; V_I = GND to 4.3 V; V_{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	-	±1	µA
$I_{S(OFF)}$	OFF-state leakage current	Y1 and Y2 port; see Fig. 4								
		V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	-	±500	nA
		V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	-	±500	nA
$I_{S(ON)}$	ON-state leakage current	Z port; see Fig. 5								
		V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	-	±500	nA
		V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	-	±500	nA
I_{CC}	supply current	V_I = V_{CC} or GND; V_{SW} = GND or V_{CC}								
		V_{CC} = 3.6 V	-	-	100	-	690	-	6000	nA
		V_{CC} = 4.3 V	-	-	150	-	800	-	7000	nA
ΔI_{CC}	additional supply current	V_{SW} = GND or V_{CC}								
		V_I = 2.6 V; V_{CC} = 4.3 V	-	2.0	4.0	-	7	-	7	µA
		V_I = 2.6 V; V_{CC} = 3.6 V	-	0.35	0.7	-	1	-	1	µA
		V_I = 1.8 V; V_{CC} = 4.3 V	-	7.0	10.0	-	15	-	15	µA
		V_I = 1.8 V; V_{CC} = 3.6 V	-	2.5	4.0	-	5	-	5	µA
		V_I = 1.8 V; V_{CC} = 2.5 V	-	50	200	-	300	-	500	nA
C_I	input capacitance		-	1.0	-	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	130	-	-	-	-	-	pF

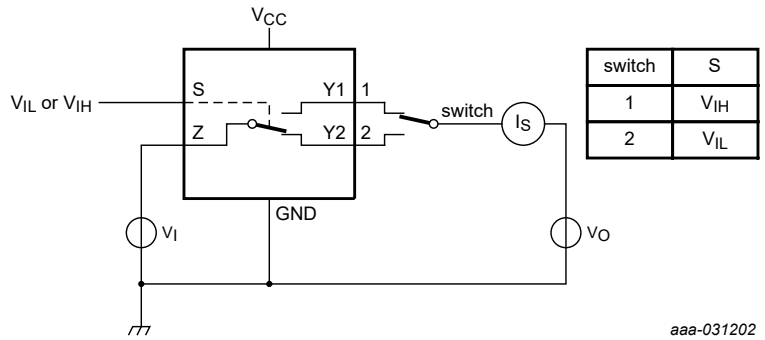
Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Fig. 7 to Fig. 13.

Symbol	Parameter	Conditions	T_{amb} = -40 °C to +85 °C			T_{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
$R_{ON(peak)}$	ON resistance (peak)	V_I = GND to V_{CC}; I_{SW} = 100 mA; see Fig. 6						
		V_{CC} = 1.4 V	-	1.6	3.7	-	4.1	Ω
		V_{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		V_{CC} = 2.3 V	-	0.55	0.8	-	0.9	Ω
		V_{CC} = 2.7 V	-	0.5	0.75	-	0.9	Ω
		V_{CC} = 4.3 V	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	V_I = GND to V_{CC}; I_{SW} = 100 mA [2]						
		V_{CC} = 1.4 V	-	0.04	0.3	-	0.3	Ω
		V_{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		V_{CC} = 2.3 V	-	0.02	0.08	-	0.1	Ω
		V_{CC} = 2.7 V	-	0.02	0.075	-	0.1	Ω
		V_{CC} = 4.3 V	-	0.02	0.075	-	0.1	Ω
$R_{ON(flat)}$	ON resistance (flatness)	V_I = GND to V_{CC}; I_{SW} = 100 mA [3]						
		V_{CC} = 1.4 V	-	1.0	3.3	-	3.6	Ω
		V_{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		V_{CC} = 2.3 V	-	0.15	0.3	-	0.35	Ω
		V_{CC} = 2.7 V	-	0.13	0.3	-	0.35	Ω
		V_{CC} = 4.3 V	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at T_{amb} = 25 °C.
[2] Measured at identical V_{CC}, temperature and input voltage.
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

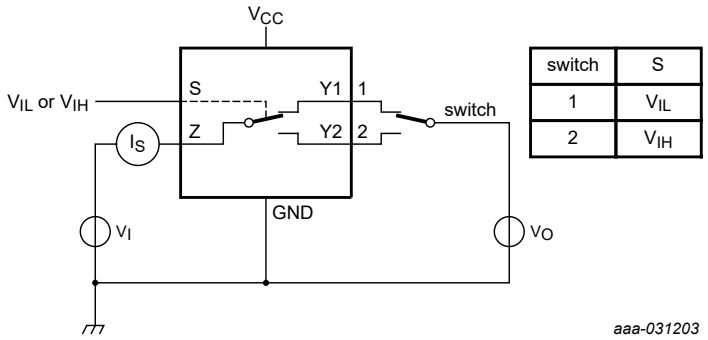
11.1. Test circuits and graphs



switch	S
1	V_{IH}
2	V_{IL}

V_I = 0.3 V or V_{CC} - 0.3 V; V_O = V_{CC} - 0.3 V or 0.3 V

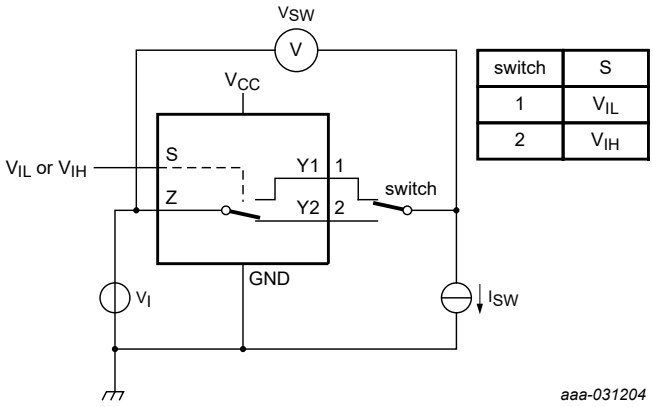
Fig. 4. Test circuit for measuring OFF-state leakage current



switch	S
1	V_{IL}
2	V_{IH}

V_I = 0.3 V or V_{CC} - 0.3 V; V_O = V_{CC} - 0.3 V or 0.3 V

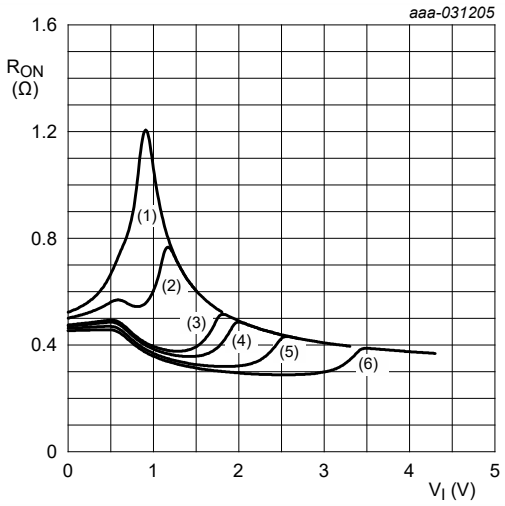
Fig. 5. Test circuit for measuring ON-state leakage current



switch	S
1	V_{IL}
2	V_{IH}

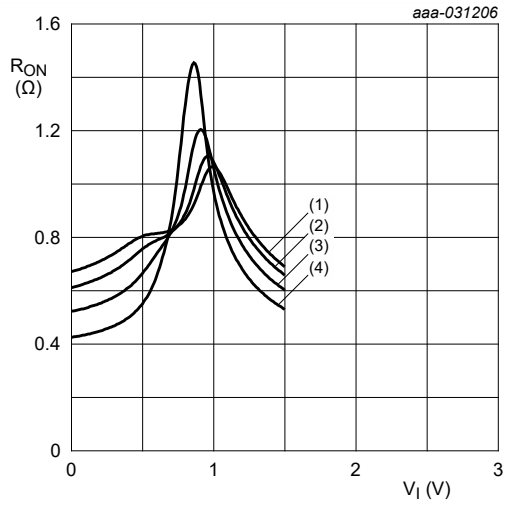
$R_{ON} = V_{SW} / I_{SW}$

Fig. 6. Test circuit for measuring ON resistance



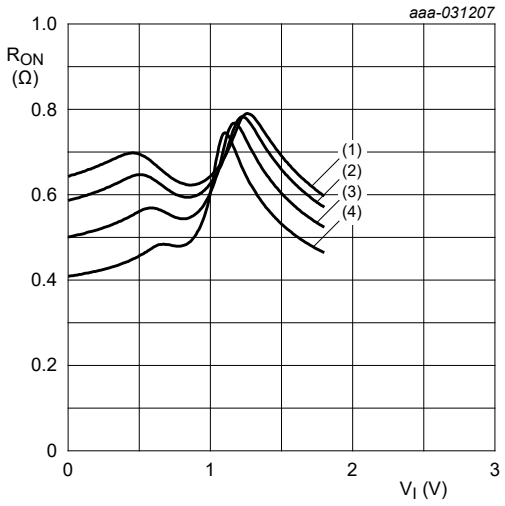
(1) V_{CC} = 1.5 V
(2) V_{CC} = 1.8 V
(3) V_{CC} = 2.5 V
(4) V_{CC} = 2.7 V
(5) V_{CC} = 3.3 V
(6) V_{CC} = 4.3 V
Measured at T_{amb} = 25 °C

Fig. 7. Typical ON resistance as a function of input voltage



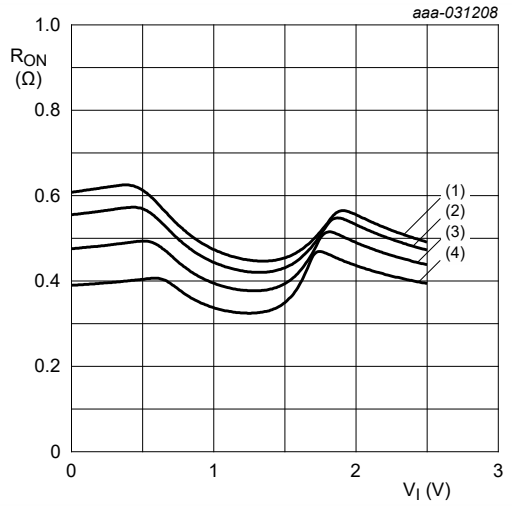
(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 8. ON resistance as a function of input voltage; V_{CC} = 1.5 V



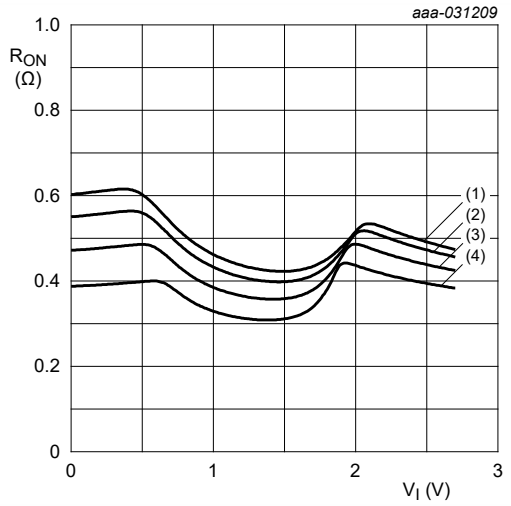
(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 9. ON resistance as a function of input voltage; V_{CC} = 1.8 V



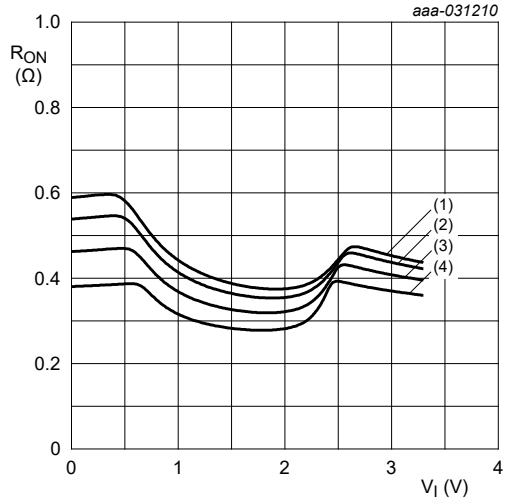
(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 10. ON resistance as a function of input voltage; V_{CC} = 2.5 V



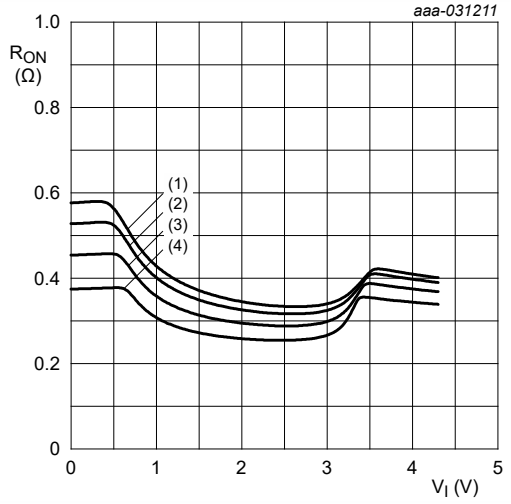
(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 11. ON resistance as a function of input voltage; V_{CC} = 2.7 V



(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 12. ON resistance as a function of input voltage; V_{CC} = 3.3 V



(1) T_{amb} = 125 °C
(2) T_{amb} = 85 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = -40 °C

Fig. 13. ON resistance as a function of input voltage; V_{CC} = 4.3 V

12. Dynamic characteristics

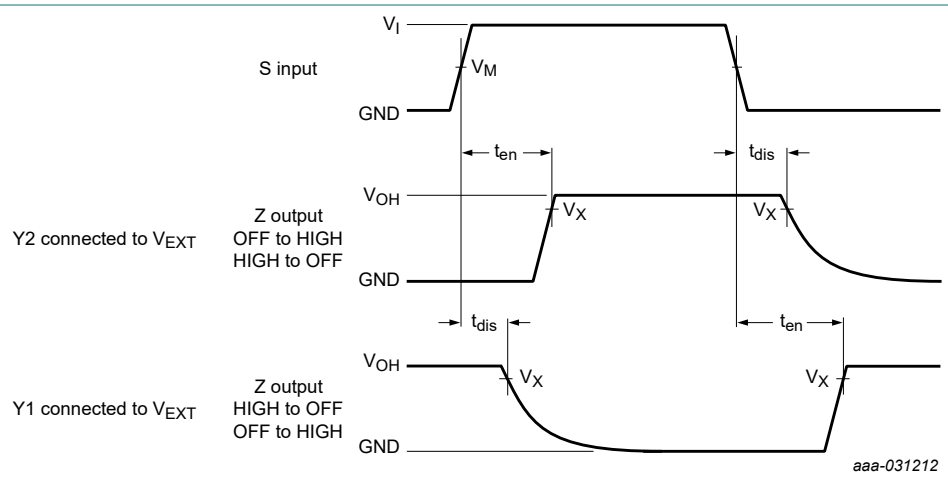
Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 16.

Symbol	Parameter	Conditions	T_{amb} = 25 °C			T_{amb} = −40 °C to +85 °C		T_{amb} = −40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t_{en}	enable time	S to Z or Yn; see Fig. 14								
		V_{CC} = 1.4 V to 1.6 V	-	50	100	-	120	-	120	ns
		V_{CC} = 1.65 V to 1.95 V	-	36	70	-	80	-	90	ns
		V_{CC} = 2.3 V to 2.7 V	-	24	45	-	50	-	55	ns
		V_{CC} = 2.7 V to 3.6 V	-	22	40	-	45	-	50	ns
		V_{CC} = 3.6 V to 4.3 V	-	22	40	-	45	-	50	ns
t_{dis}	disable time	S to Z or Yn; see Fig. 14								
		V_{CC} = 1.4 V to 1.6 V	-	32	80	-	80	-	90	ns
		V_{CC} = 1.65 V to 1.95 V	-	20	55	-	60	-	65	ns
		V_{CC} = 2.3 V to 2.7 V	-	12	25	-	30	-	35	ns
		V_{CC} = 2.7 V to 3.6 V	-	10	20	-	25	-	30	ns
		V_{CC} = 3.6 V to 4.3 V	-	10	20	-	25	-	30	ns
t_{b-m}	break-before-make time	see Fig. 15 [2]								
		V_{CC} = 1.4 V to 1.6 V	-	19	-	9	-	9	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	17	-	7	-	7	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	13	-	4	-	4	-	ns
		V_{CC} = 2.7 V to 3.6 V	-	10	-	3	-	3	-	ns
		V_{CC} = 3.6 V to 4.3 V	-	10	-	2	-	2	-	ns

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.
[2] Break-before-make guaranteed by design.

12.1. Waveforms and test circuit



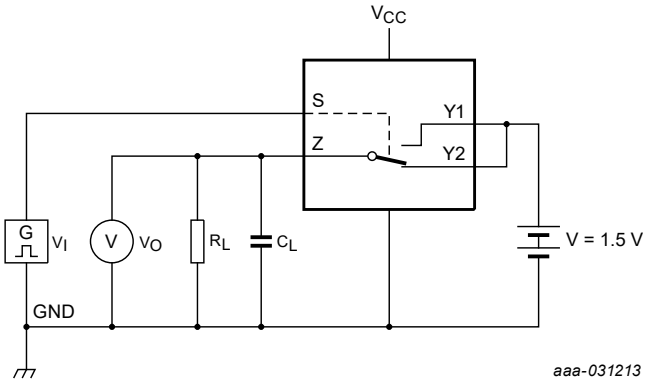
Measurement points are given in Table 10.

Logic level: V_{OH} is typical output voltage level that occurs with the output load.

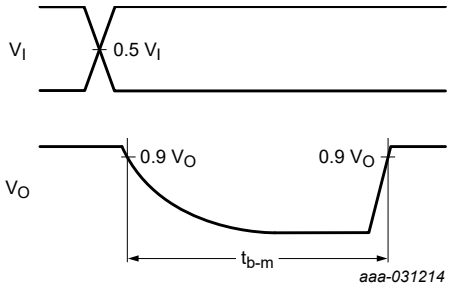
Fig. 14. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_X
1.4 V to 4.3 V	$0.5V_{CC}$	$0.9V_{OH}$

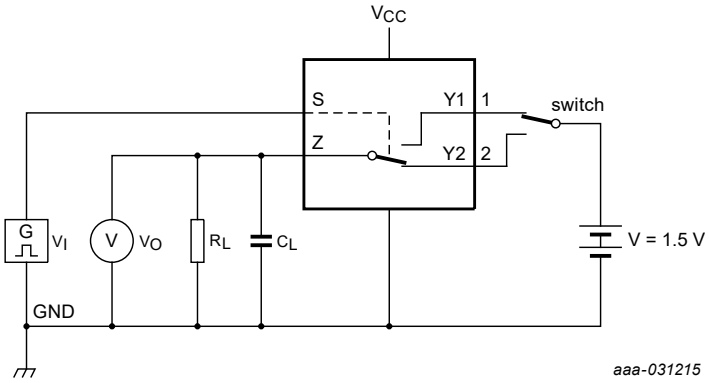


a. Test circuit



b. Input and output measurement points

Fig. 15. Test circuit for measuring break-before-make times



Test data is given in Table 11.

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

V_{EXT} = External voltage for measuring switching times.

Fig. 16. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input		Load	
V_{CC}	V_I	t_r, t_f	C_L	R_L
1.4 V to 4.3 V	V_{CC}	≤ 2.5 ns	35 pF	50 Ω

12.2. Additional dynamic characteristics

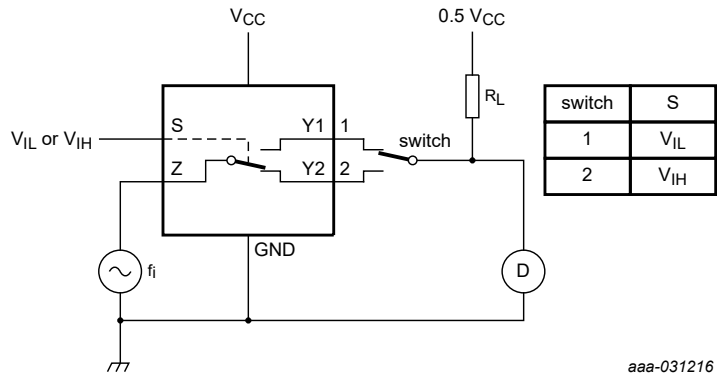
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); $t_r = t_f \leq 2.5$ ns; T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	f_i = 20 Hz to 20 kHz; R_L = 32 Ω; see Fig. 17 [1]				
		V_{CC} = 1.4 V; V_I = 1 V (p-p)	-	0.15	-	%
		V_{CC} = 1.65 V; V_I = 1.2 V (p-p)	-	0.10	-	%
		V_{CC} = 2.3 V; V_I = 1.5 V (p-p)	-	0.04	-	%
		V_{CC} = 2.7 V; V_I = 2 V (p-p)	-	0.03	-	%
		V_{CC} = 4.3 V; V_I = 2 V (p-p)	-	0.01	-	%
$f_{(-3dB)}$	-3 dB frequency response	R_L = 50 Ω; see Fig. 18 [1]				
		V_{CC} = 1.4 V to 4.3 V	-	40	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 100 kHz; R_L = 50 Ω; see Fig. 19 [1]				
		V_{CC} = 1.4 V to 4.3 V	-	-90	-	dB
V_{ct}	crosstalk voltage	between digital inputs and switch; f_i = 1 MHz; C_L = 50 pF; R_L = 50 Ω; see Fig. 20 [1]				
		V_{CC} = 1.4 V to 3.6 V	-	0.4	-	V
		V_{CC} = 3.6 V to 4.3 V	-	0.6	-	V
Q_{inj}	charge injection	f_i = 1 MHz; C_L = 0.1 nF; R_L = 1 MΩ; V_{gen} = 0 V; R_{gen} = 0 Ω; see Fig. 21 [1]				
		V_{CC} = 1.5 V	-	3	-	pC
		V_{CC} = 1.8 V	-	4	-	pC
		V_{CC} = 2.5 V	-	6	-	pC
		V_{CC} = 3.3 V	-	9	-	pC
		V_{CC} = 4.3 V	-	15	-	pC

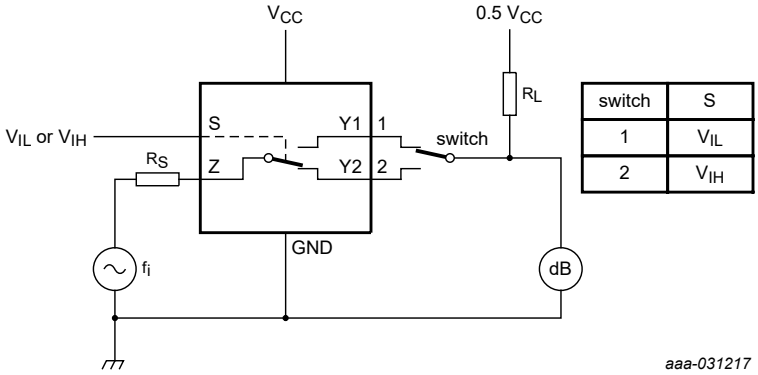
[1] f_i is biased at $0.5V_{CC}$.

12.3. Additional test circuits



switch	S
1	V_{IL}
2	V_{IH}

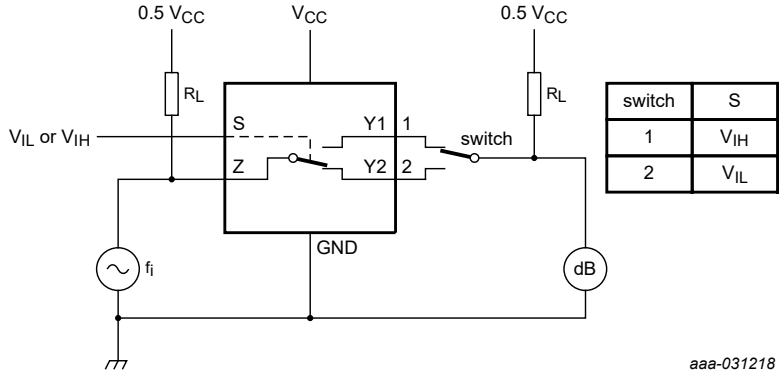
Fig. 17. Test circuit for measuring total harmonic distortion



switch	S
1	V_{IL}
2	V_{IH}

Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.
$R_S = R_L = 50\ \Omega$ (standard 50 Ω system).

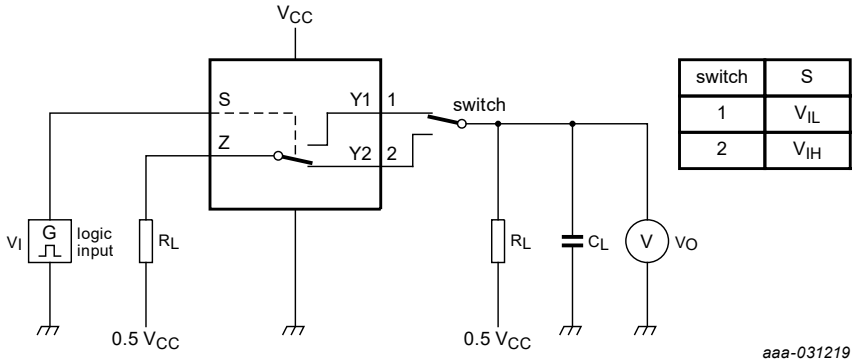
Fig. 18. Test circuit for measuring the frequency response when channel is in ON-state



switch	S
1	V_{IH}
2	V_{IL}

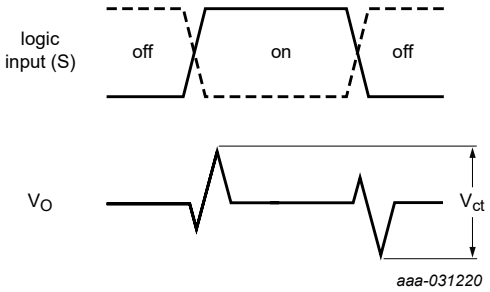
Adjust f_i voltage to obtain 0 dBm level at input.

Fig. 19. Test circuit for measuring isolation (OFF-state)



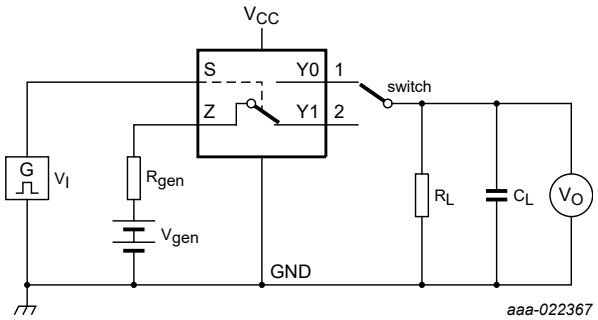
switch	S
1	V_{IL}
2	V_{IH}

a. Test circuit

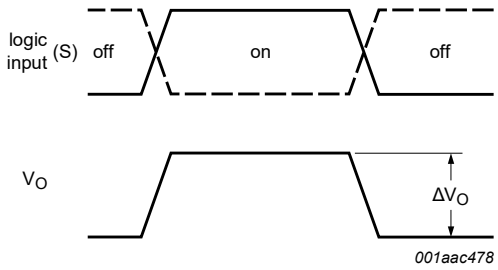


b. Input and output pulse definitions

Fig. 20. Test circuit for measuring crosstalk voltage between digital input and switch



a. Test circuit



b. Input and output pulse definitions

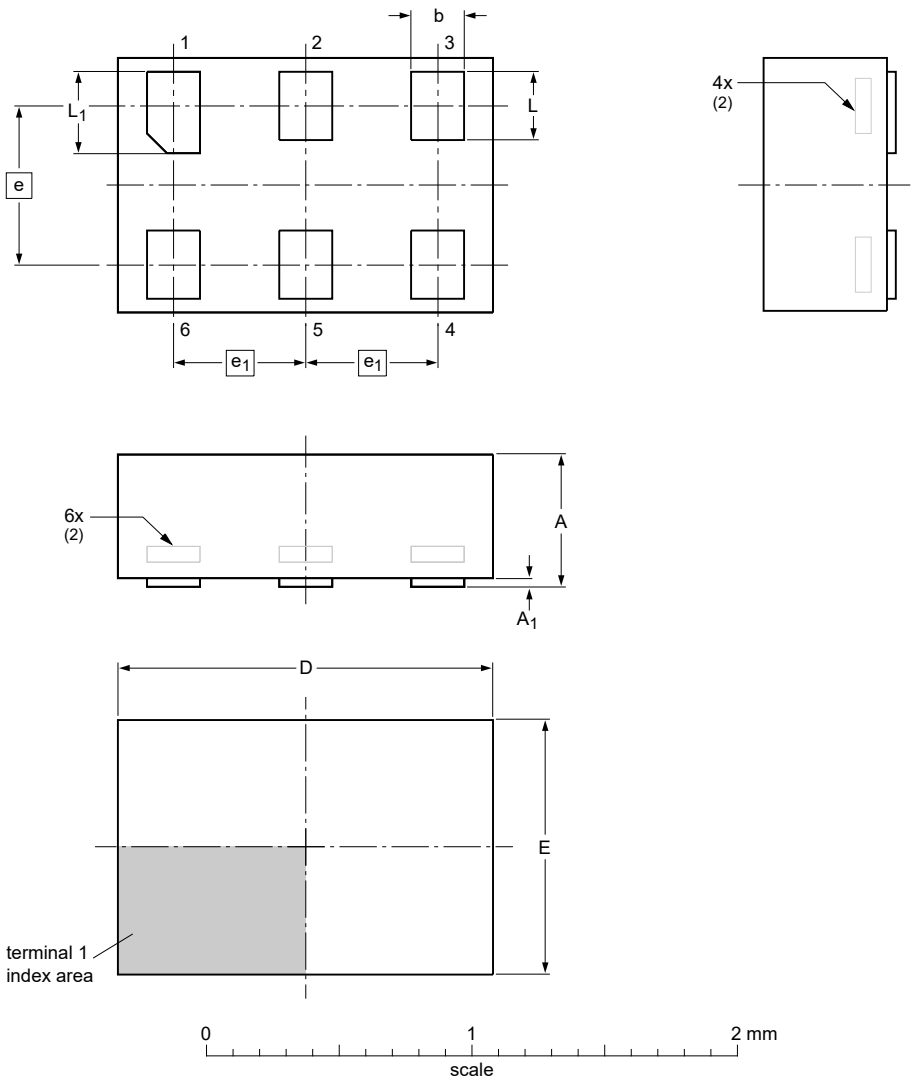
$Q_{inj} = \Delta V_O \times C_L$.
ΔV_O = output voltage variation.
R_{gen} = generator resistance.
V_{gen} = generator voltage.

Fig. 21. Test circuit for measuring charge injection

13. Package outline

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



Dimensions (mm are the original dimensions)

Unit		A(1)	A_1	b	D	E	e	e_1	L	L_1
	max	0.5	0.04	0.25	1.50	1.05			0.35	0.40
mm	nom			0.20	1.45	1.00	0.6	0.5	0.30	0.35
	min			0.17	1.40	0.95			0.27	0.32

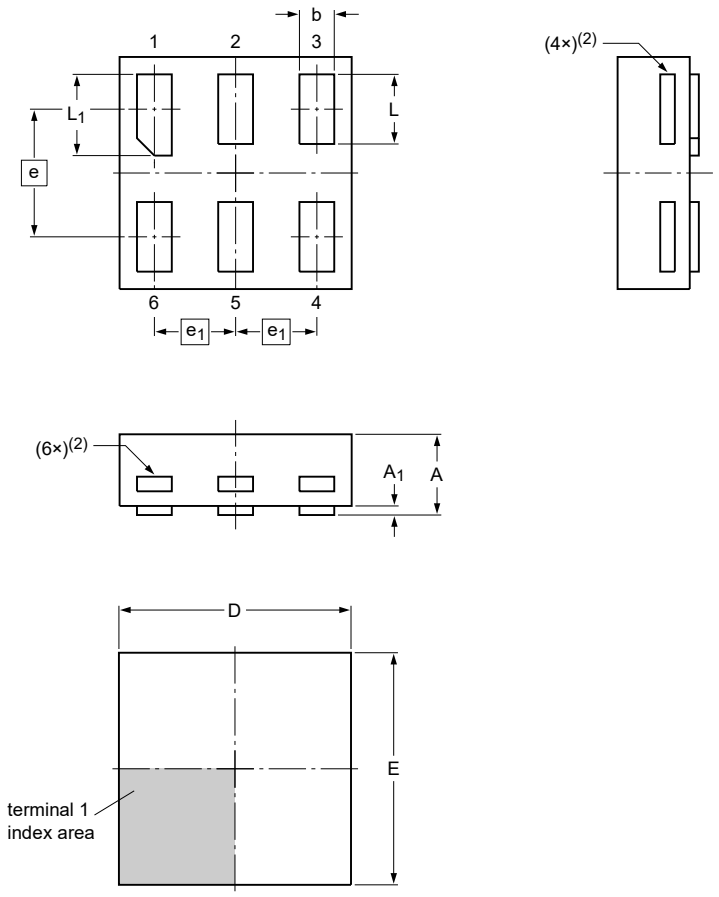
Notes
1. Including plating thickness.
2. Can be visible in some manufacturing processes.

sot886_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT886		MO-252				~~04-07-22~~ 12-01-05

Fig. 22. Package outline SOT886 (XSON6)

XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm **SOT1202**



Dimensions

Unit		A(1)	A1	b	D	E	e	e1	L	L1
mm	max	0.35	0.04	0.20	1.05	1.05			0.35	0.40
	nom			0.15	1.00	1.00	0.55	0.35	0.30	0.35
	min			0.12	0.95	0.95			0.27	0.32

Note
1. Including plating thickness.
2. Visible depending upon used manufacturing technology.

sot1202_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1202						~~10-04-02~~ 10-04-06

Fig. 23. Package outline SOT1202 (XSON6)

14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
XS3A1T3157 v.1	20200317	Product data sheet	-	-

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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